

# 7MBR150VN120-50

**IGBT Modules**

## IGBT MODULE (V series)

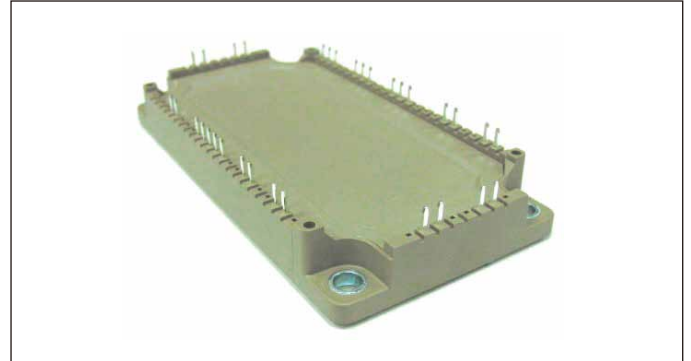
### 1200V / 150A / PIM

#### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant product

#### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply



#### ■ Maximum Ratings and Characteristics

##### ● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage	$V_{CES}$			1200	V
	Gate-Emitter voltage	$V_{GES}$			$\pm 20$	V
	Collector current	$I_c$	Continuous	$T_c=100^\circ\text{C}$	150	A
		$I_{cp}$	1ms	$T_c=80^\circ\text{C}$	300	
		$-I_c$			150	
$-I_c$ pulse		1ms			300	
Collector power dissipation	$P_c$	1 device		885	W	
Brake	Collector-Emitter voltage	$V_{CES}$			1200	V
	Gate-Emitter voltage	$V_{GES}$			$\pm 20$	V
	Collector current	$I_c$	Continuous	$T_c=80^\circ\text{C}$	100	A
		$I_{cp}$	1ms	$T_c=80^\circ\text{C}$	200	
	Collector power dissipation	$P_c$	1 device		520	W
Repetitive peak reverse voltage (Diode)	$V_{RRM}$			1200	V	
Converter	Repetitive peak reverse voltage	$V_{RRM}$			1600	V
	Average output current	$I_o$	50Hz/60Hz, sine wave		150	A
	Surge current (Non-Repetitive)	$I_{FSM}$	10ms, $T_j=150^\circ\text{C}$		780	A
	$I^2t$ (Non-Repetitive)	$I^2t$	half sine wave		3000	$\text{A}^2\text{s}$
Junction temperature	$T_j$	Inverter, Brake		175	$^\circ\text{C}$	
		Converter		150		
Operating junction temperature (under switching conditions)	$T_{jop}$	Inverter, Brake		150		
		Converter		150		
Case temperature	$T_c$			125		
Storage temperature	$T_{stg}$			-40 to +125		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	$V_{iso}$	AC : 1min.		2500	VAC
Screw torque	Mounting (*3)	-	M5		3.5	N m

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note \*3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

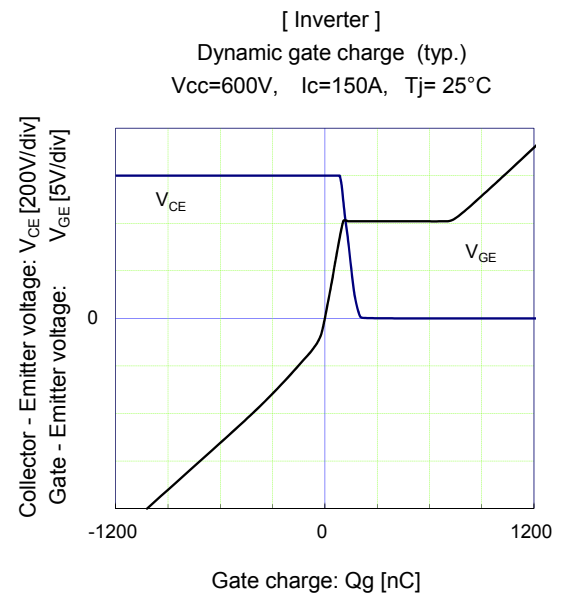
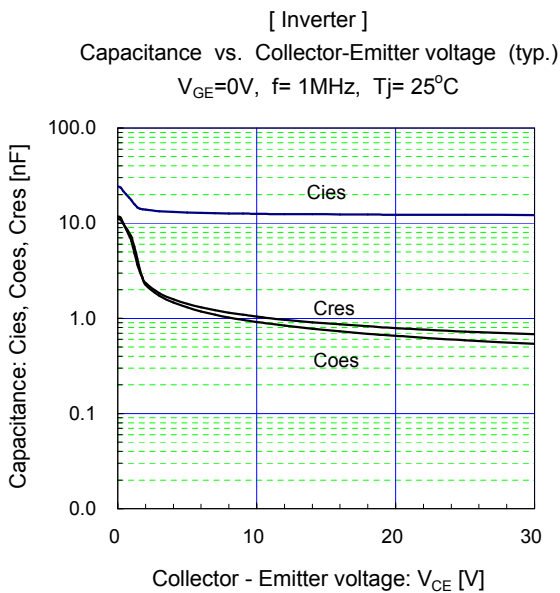
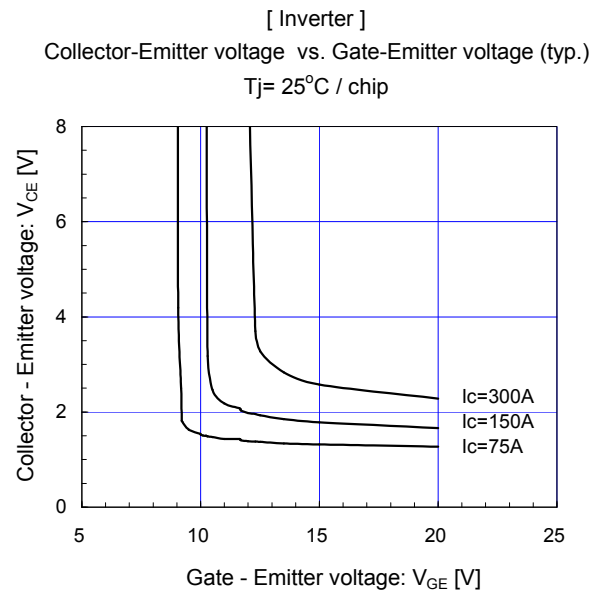
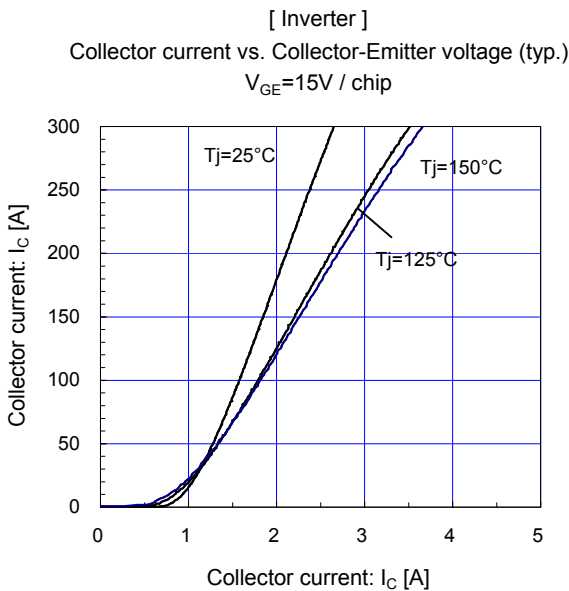
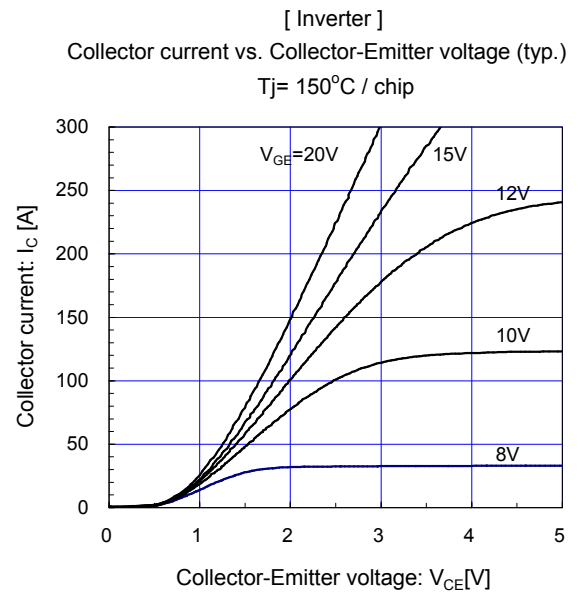
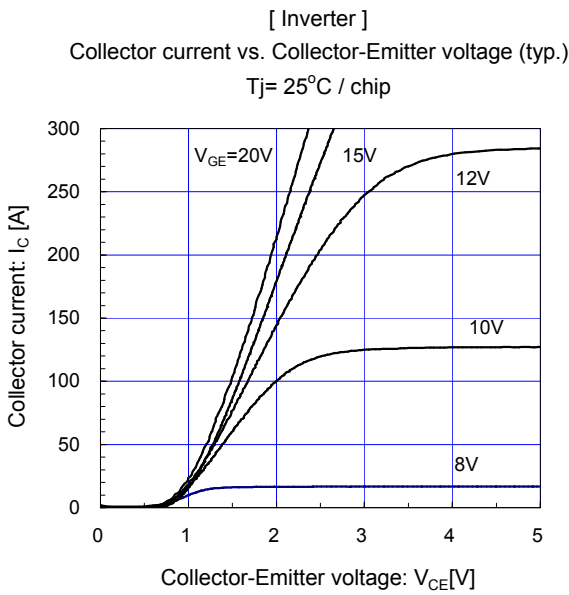
Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Inverter	Zero gate voltage collector current	I <sub>CES</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V	-	-	1.0	mA	
	Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = ±20V	-	-	200	nA	
	Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 20V, I <sub>c</sub> = 150mA	6.0	6.5	7.0	V	
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 150A	T <sub>j</sub> = 25°C	-	2.45	2.90	V
				T <sub>j</sub> = 125°C	-	2.80	-	
				T <sub>j</sub> = 150°C	-	2.85	-	
		V <sub>CE(sat)</sub> (chip)	V <sub>GE</sub> = 15V I <sub>c</sub> = 150A	T <sub>j</sub> = 25°C	-	1.85	2.30	
				T <sub>j</sub> = 125°C	-	2.20	-	
	T <sub>j</sub> = 150°C	-	2.25	-				
	Internal gate resistance	R <sub>g(int)</sub>	-	-	5	-	Ω	
	Input capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz	-	12.5	-	nF	
	Turn-on time	ton	V <sub>CC</sub> = 600V I <sub>c</sub> = 150A V <sub>GE</sub> = +15 / -15V R <sub>G</sub> = 1.8Ω	-	0.39	1.20	μs	
		tr		-	0.09	0.60		
		tr(i)		-	0.03	-		
	Turn-off time	toff	R <sub>G</sub> = 1.8Ω	-	0.53	1.00	μs	
tf		-		0.06	0.30			
Forward on voltage	V <sub>F</sub> (terminal)	I <sub>F</sub> = 150A	T <sub>j</sub> = 25°C	-	2.50	2.95	V	
			T <sub>j</sub> = 125°C	-	2.80	-		
			T <sub>j</sub> = 150°C	-	2.75	-		
	V <sub>F</sub> (chip)	I <sub>F</sub> = 150A	T <sub>j</sub> = 25°C	-	1.90	2.35		
			T <sub>j</sub> = 125°C	-	2.20	-		
T <sub>j</sub> = 150°C	-	2.15	-					
Reverse recovery time	trr	I <sub>F</sub> = 150A	-	-	0.35	μs		
Brake	Zero gate voltage collector current	I <sub>CES</sub>	V <sub>GE</sub> = 0V V <sub>CE</sub> = 1200V	-	-	1.0	mA	
	Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>CE</sub> = 0V V <sub>GE</sub> = +20 / -20V	-	-	200	nA	
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 100A	T <sub>j</sub> = 25°C	-	2.15	2.60	V
				T <sub>j</sub> = 125°C	-	2.45	-	
				T <sub>j</sub> = 150°C	-	2.50	-	
		V <sub>CE(sat)</sub> (chip)	V <sub>GE</sub> = 15V I <sub>c</sub> = 100A	T <sub>j</sub> = 25°C	-	1.75	2.20	
				T <sub>j</sub> = 125°C	-	2.05	-	
	T <sub>j</sub> = 150°C	-	2.10	-				
	Internal gate resistance	R <sub>g(int)</sub>	-	-	7.5	-	Ω	
	Turn-on time	ton	V <sub>CE</sub> = 600V I <sub>c</sub> = 100A V <sub>GE</sub> = +15 / -15V R <sub>G</sub> = 1.6Ω	-	0.39	1.20	μs	
tr		-		0.09	0.60			
Turn-off time	toff	R <sub>G</sub> = 1.6Ω	-	0.53	1.00	μs		
	tf		-	0.06	0.30			
Reverse current	IRRM	V <sub>R</sub> = 1200V	-	-	1.00	mA		
Converter	Forward on voltage	I <sub>F</sub> = 150A	terminal	-	2.00	2.45	V	
			chip	-	1.40	-		
Reverse current	IRRM	V <sub>R</sub> = 1600V	-	-	1.0	mA		
Thermistor	Resistance	T = 25°C	-	5000	-	Ω		
		T = 100°C	465	495	520			
	B value	B	T = 25 / 50°C	3305	3375	3450	K	

## ● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	R <sub>th(j-c)</sub>	Inverter IGBT	-	-	0.17	°C/W
		Inverter FWD	-	-	0.31	
		Brake IGBT	-	-	0.29	
		Converter Diode	-	-	0.24	
Contact thermal resistance (1device) (*4)	R <sub>th(c-f)</sub>	with Thermal Compound	-	0.05	-	

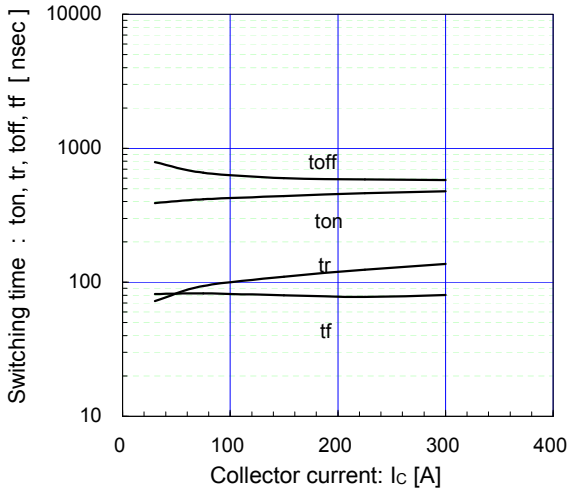
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)



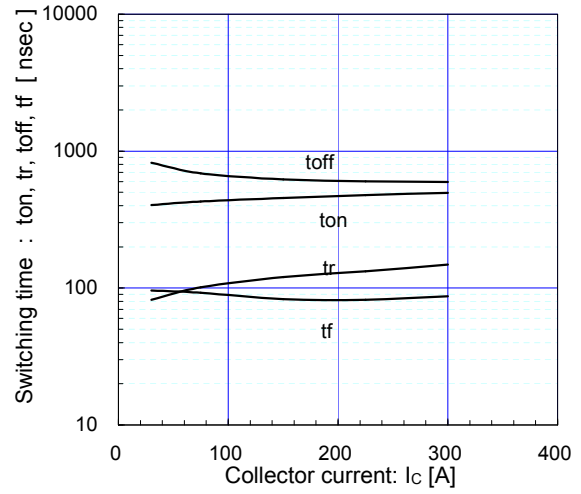
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_g=1.8\Omega, T_j=125^\circ C$



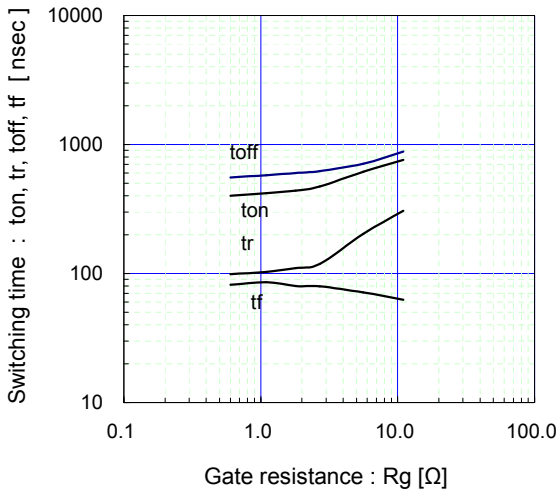
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_g=1.8\Omega, T_j=150^\circ C$



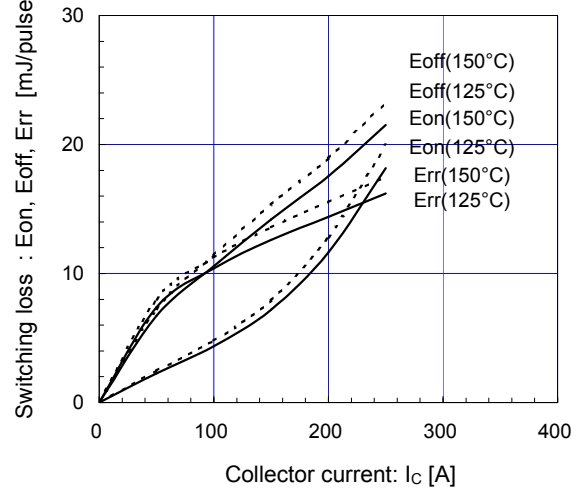
[ Inverter ]

Switching time vs. gate resistance (typ.)  
 $V_{CC}=600V, I_C=150A, V_{GE}=\pm 15V, T_j=125^\circ C$



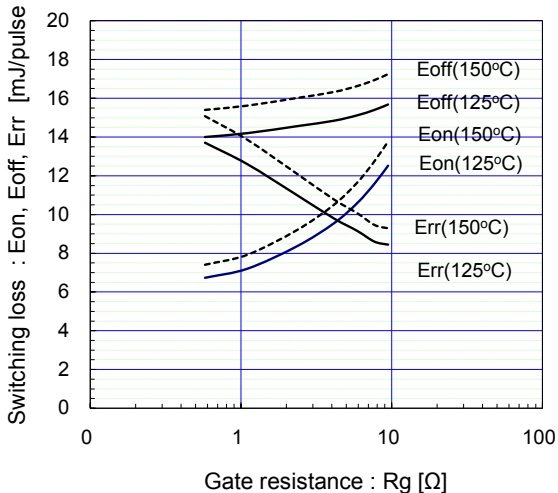
[ Inverter ]

Switching loss vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_g=1.8\Omega$



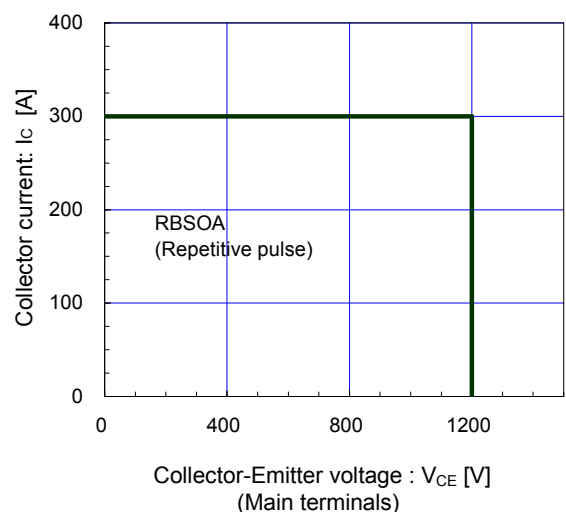
[ Inverter ]

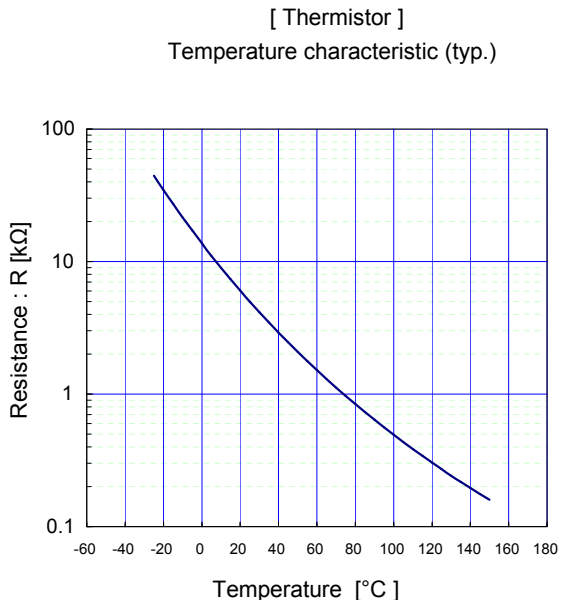
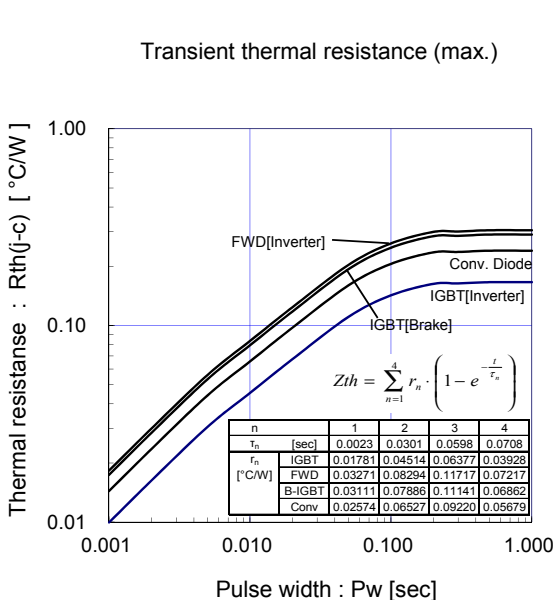
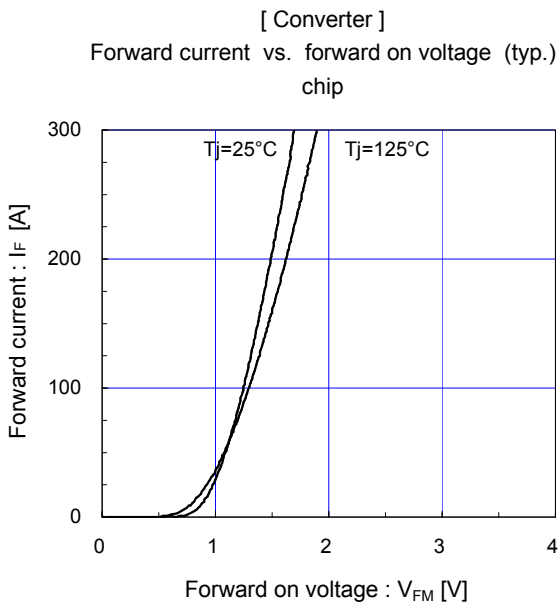
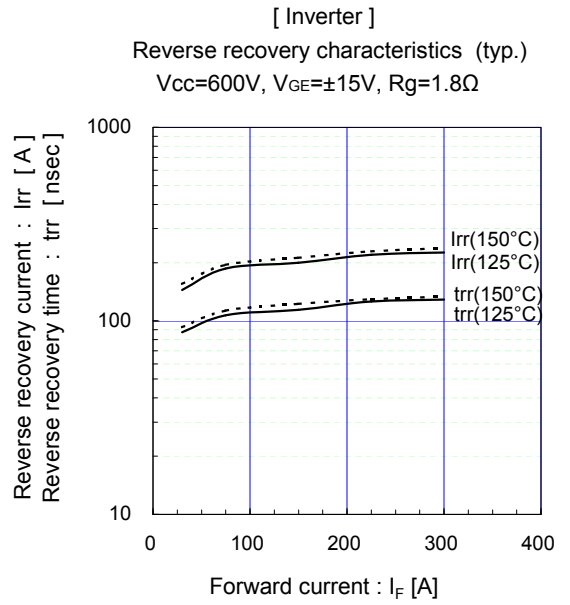
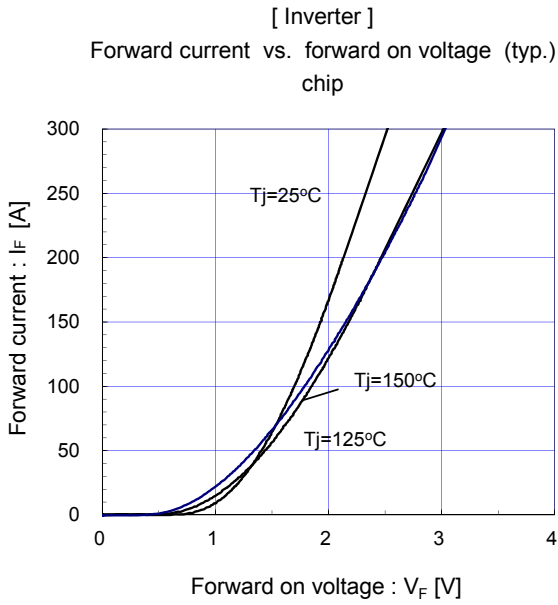
Switching loss vs. gate resistance (typ.)  
 $V_{CC}=600V, I_C=150A, V_{GE}=\pm 15V$

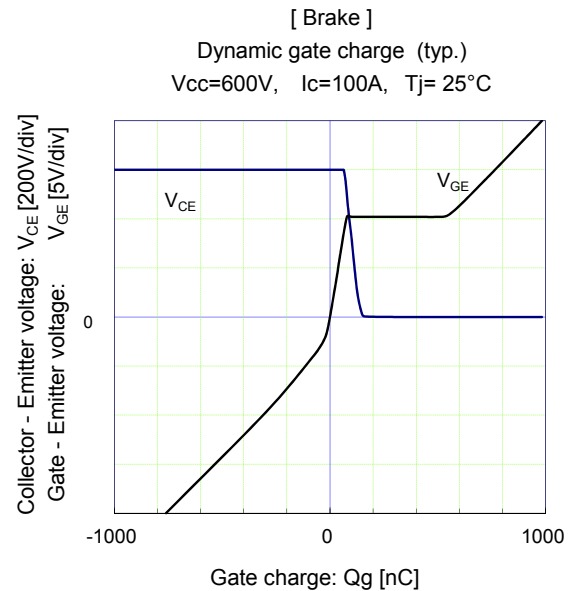
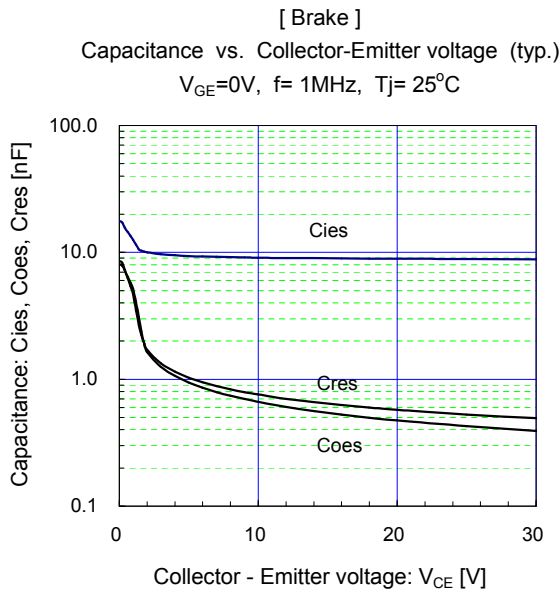
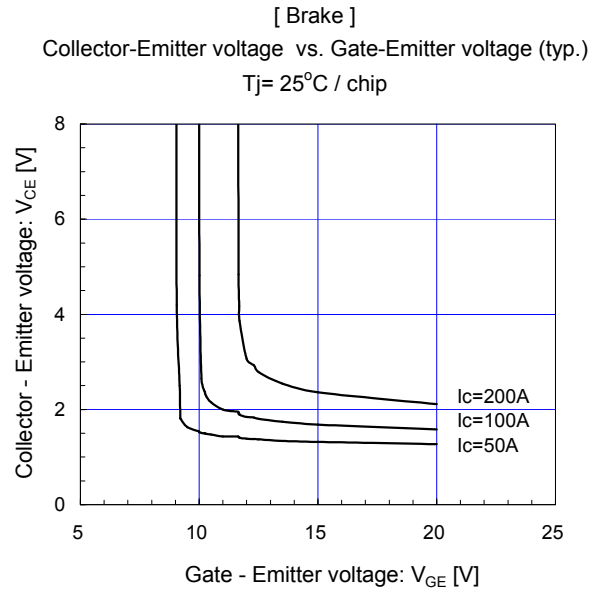
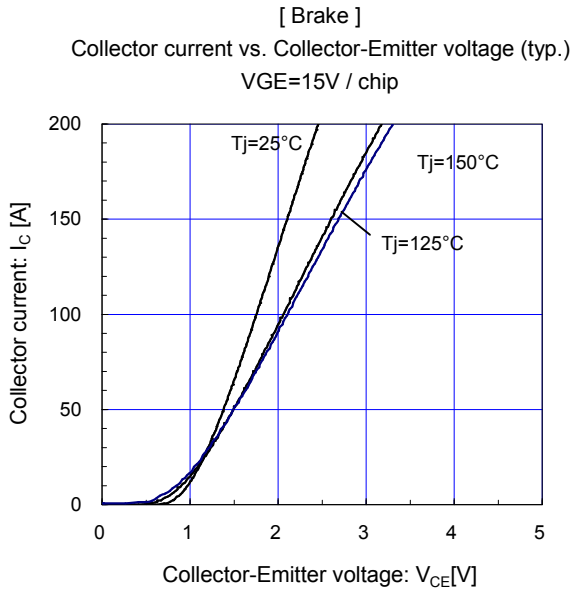
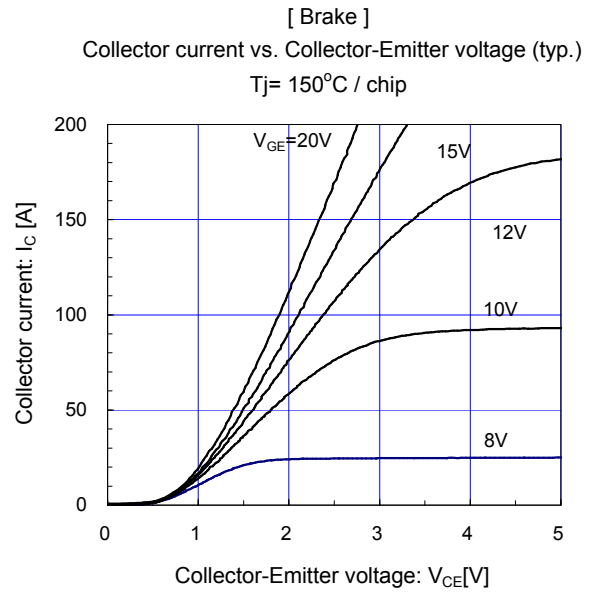
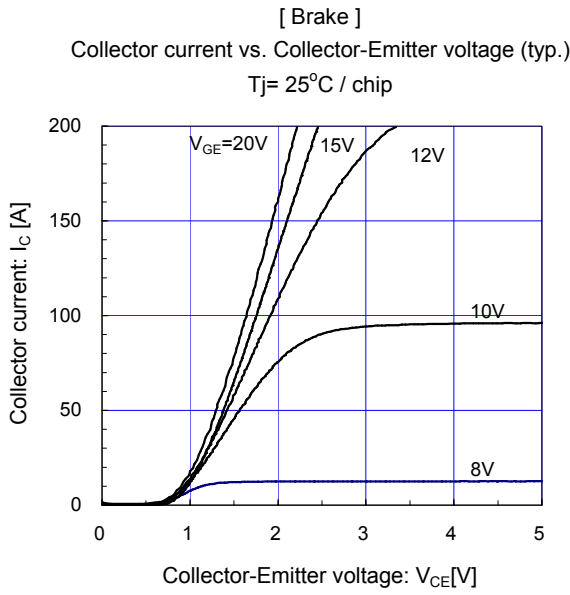


[ Inverter ]

Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE} \leq 15V, R_g \geq 1.8\Omega, T_j=150^\circ C$

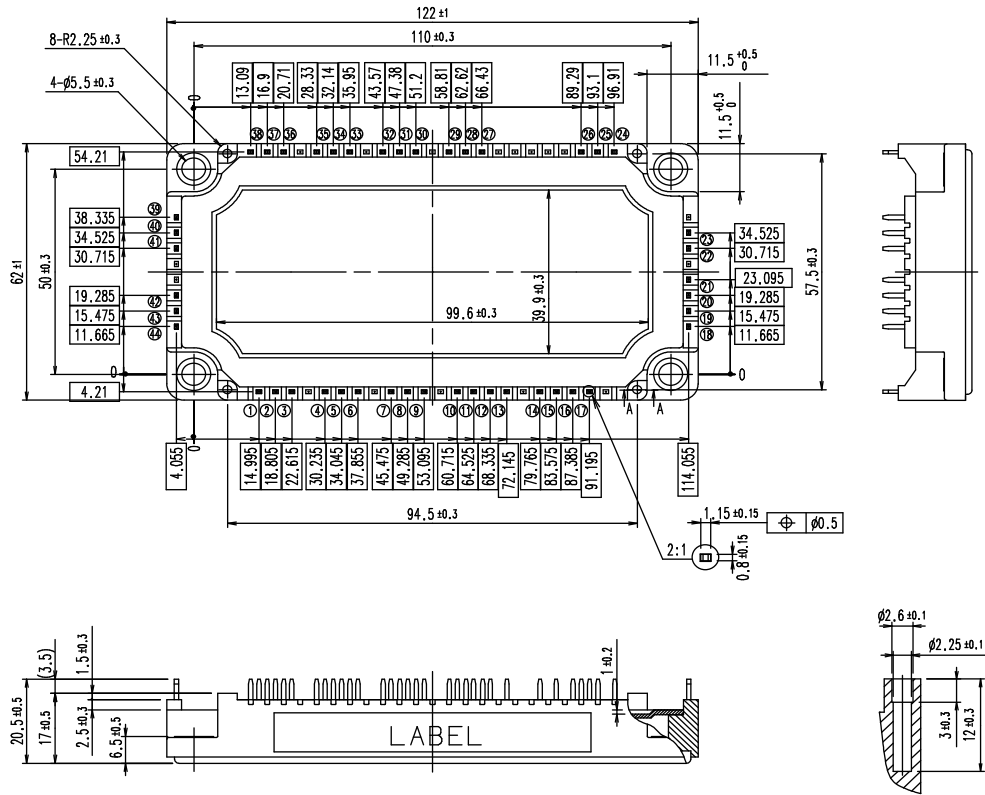






Outline Drawings (Unit: mm)

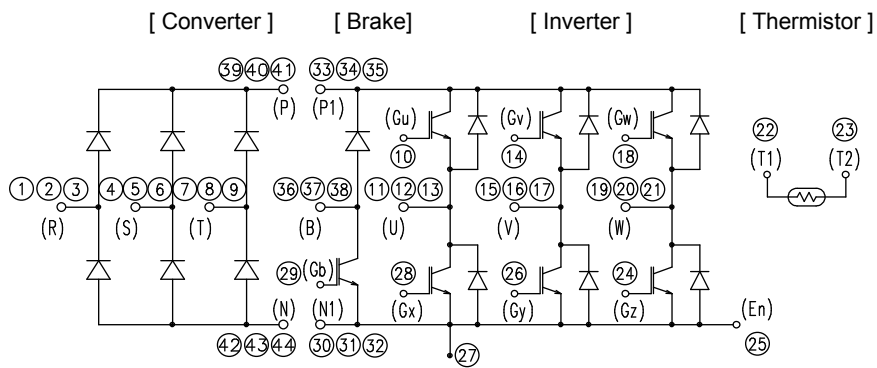
□ shows theoretical dimension.  
 ( ) shows reference dimension.



Section A-A

Weight: 310g(typ.)

Equivalent Circuit



**WARNING**

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of July 2015. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications.
2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Co., Ltd. is (or shall be deemed) granted. Fuji Electric Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.
3. Although Fuji Electric Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design failsafe, flame retardant, and free of malfunction.
4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
  - Computers
  - OA equipment
  - Communications equipment (terminal devices)
  - Measurement equipment
  - Machine tools
  - Audiovisual equipment
  - Electrical home appliances
  - Personal equipment
  - Industrial robots etc.
5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
  - Transportation equipment (mounted on cars and ships)
  - Trunk communications equipment
  - Traffic-signal control equipment
  - Gas leakage detectors with an auto-shut-off feature
  - Emergency equipment for responding to disasters and anti-burglary devices
  - Safety devices
  - Medical equipment
6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
  - Space equipment
  - Aeronautic equipment
  - Nuclear control equipment
  - Submarine repeater equipment
7. Copyright ©1996-2015 by Fuji Electric Co., Ltd. All rights reserved.  
No part of this Catalog may be reproduced in any form or by any means without the express permission of Fuji Electric Co., Ltd.
8. If you have any question about any portion in this Catalog, ask Fuji Electric Co., Ltd. or its sales agents before using the product. Neither Fuji Electric Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.



# Technical Information

**IGBT Modules**

- Please refer to URLs below for further information about products, application manuals and technical documents.
- 关于本规格书中没有记载的产品信息·应用手册·技术资料等·请参考以下链接。
- 本データシートに記載されていない製品情報，アプリケーションマニュアル，技術資料は以下の URL をご参照下さい。

## FUJI ELECTRIC Power Semiconductor WEB site

日本	<a href="http://www.fujielectric.co.jp/products/semiconductor/">www.fujielectric.co.jp/products/semiconductor/</a>
Global	<a href="http://www.fujielectric.com/products/semiconductor/">www.fujielectric.com/products/semiconductor/</a>
中国	<a href="http://www.fujielectric.com.cn/products/semiconductor/">www.fujielectric.com.cn/products/semiconductor/</a>
Europe	<a href="http://www.fujielectric-europe.com/components/semiconductors/">www.fujielectric-europe.com/components/semiconductors/</a>
North America	<a href="http://www.americas.fujielectric.com/components/semiconductors/">www.americas.fujielectric.com/components/semiconductors/</a>

## Information

### 日本

1 半導体総合カタログ	<a href="http://www.fujielectric.co.jp/products/semiconductor/catalog/">www.fujielectric.co.jp/products/semiconductor/catalog/</a>
2 製品情報	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/">www.fujielectric.co.jp/products/semiconductor/model/</a>
3 アプリケーションマニュアル	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/application/">www.fujielectric.co.jp/products/semiconductor/model/igbt/application/</a>
4 技術資料	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/">www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/</a>
5 マウンティングインストラクション	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/">www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 損失シミュレーションソフト	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/">www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level 損失シミュレーションソフト	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation_3level/</a>
8 富士電機技報	<a href="http://www.fujielectric.co.jp/products/semiconductor/journal/">www.fujielectric.co.jp/products/semiconductor/journal/</a>
9 製品のお問い合わせ	<a href="http://www.fujielectric.co.jp/products/semiconductor/contact/">www.fujielectric.co.jp/products/semiconductor/contact/</a>
10 改廃のお知らせ	<a href="http://www.fujielectric.co.jp/products/semiconductor/discontinued/">www.fujielectric.co.jp/products/semiconductor/discontinued/</a>

### Global

1 Semiconductors General Catalog	<a href="http://www.fujielectric.com/products/semiconductor/catalog/">www.fujielectric.com/products/semiconductor/catalog/</a>
2 Product Information	<a href="http://www.fujielectric.com/products/semiconductor/model/">www.fujielectric.com/products/semiconductor/model/</a>
3 Application Manuals	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/application/">www.fujielectric.com/products/semiconductor/model/igbt/application/</a>
4 Technical Documents	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/technical/">www.fujielectric.com/products/semiconductor/model/igbt/technical/</a>
5 Mounting Instructions	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/mounting/">www.fujielectric.com/products/semiconductor/model/igbt/mounting/</a>
6 IGBT Loss Simulation Software	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/simulation/">www.fujielectric.com/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level Loss Simulation Software	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.com/products/semiconductor/model/igbt/simulation_3level/</a>
8 Fuji Electric Journal	<a href="http://www.fujielectric.com/products/semiconductor/journal/">www.fujielectric.com/products/semiconductor/journal/</a>
9 Contact	<a href="http://www.fujielectric.com/products/semiconductor/contact/">www.fujielectric.com/products/semiconductor/contact/</a>
10 Revised and discontinued product information	<a href="http://www.fujielectric.com/products/semiconductor/discontinued/">www.fujielectric.com/products/semiconductor/discontinued/</a>

### 中国

1 半导体综合目录	<a href="http://www.fujielectric.com.cn/products/semiconductor/catalog/">www.fujielectric.com.cn/products/semiconductor/catalog/</a>
2 产品信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/">www.fujielectric.com.cn/products/semiconductor/model/</a>
3 应用手册	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/application/">www.fujielectric.com.cn/products/semiconductor/model/igbt/application/</a>
4 技术资料	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/">www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/</a>
5 安装说明书	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/">www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation_3level/</a>
8 富士电机技报	<a href="http://www.fujielectric.com.cn/products/semiconductor/journal/">www.fujielectric.com.cn/products/semiconductor/journal/</a>
9 产品咨询	<a href="http://www.fujielectric.com.cn/products/semiconductor/contact/">www.fujielectric.com.cn/products/semiconductor/contact/</a>
10 产品更改和停产信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/discontinued/">www.fujielectric.com.cn/products/semiconductor/discontinued/</a>